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We Claim:

- A method for the production of a nanoscale particle array, comprising:
 growing one or more metals or non-metals in a plurality of nanopores located in a surface of a substrate, wherein said growing is performed by reverse-pulse electrodeposition using a rectangular waveform pulse.
- The method of claim 1, wherein said rectangular waveform pulse has a peak-topeak amplitude of 20 to 100 V for a cathodic portion of the pulse and a peak-topeak amplitude of 20 to 100 V for an anodic portion of the pulse.
- The method of claim 2, wherein said rectangular waveform pulse has an overall duration of 10⁻⁴ to 10⁻² s.
- The method of claim 3, wherein said rectangular waveform pulse has a frequency of 1 to 10⁴ Hz.
- The method of claim 1, wherein said rectangular waveform pulse is a symmetrical pulse.
- The method of claim 1, wherein said rectangular waveform pulse is an asymmetrical pulse.
- The method of claim 1, wherein said one or more metals are selected from the group consisting of magnetic metals, non-magnetic metals, semiconductors and metal oxides.
- The method of claim 7, wherein said one or more metals are selected from the group consisting of magnetic metals and alloys thereof.
- The method of claim 8, wherein said magnetic metals are selected from the group consisting of Fe, Co, Ni and alloys thereof.
- 10. The method of claim 1, wherein said substrate is aluminum.

- 11. The method aim 1, wherein said plurality of nanopales are present in said substrate at a density of from 10⁶ to 10¹² cm⁻².
- 12. A method for producing nanoscale particle arrays, comprising: forming a plurality of nanopores in a surface of a substrate; and growing one or more metals or non-metals in said plurality of nanopores, wherein said growing is performed by reverse-pulse electrodeposition using a rectangular waveform pulse.
- 13. The method of claim 12, wherein said rectangular waveform pulse has a peak-to-peak amplitude of 20 to 100 V for a cathodic portion of the pulse and a peak-to-peak amplitude of 20 to 100 V for an anodic portion of the pulse.
- 14. The method of claim 13, wherein said rectangular waveform pulse has an overall duration of 10⁻⁴ to 10⁻² s.
- 15. The method of claim 14, wherein said rectangular waveform pulse has a frequency of 1 to 10⁴ Hz.
- 16. The method of claim 12, wherein said rectangular waveform pulse is a symmetrical pulse.
- The method of claim 12, wherein said rectangular waveform pulse is an asymmetrical pulse.
- 18. The method of claim 12, wherein said one or more metals are selected from the group consisting of magnetic metals, non-magnetic metals, semiconductors and metal oxides.
- 19. The method of claim 18, wherein said one or more metals are selected from the group consisting of magnetic metals and alloys thereof.
- The method of claim 19, wherein said magnetic metals are selected from the group consisting of Fe, Co, Ni and alloys thereof.

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- 21. The method claim 12, wherein said substrate is a sinum
- 22. The method of claim 12, wherein said plurality of nanopores are present in said substrate at a density of from 10⁶ to 10¹² cm².
- 23. The method of claim 12, wherein said forming step is performed by anodization of the surface of the substrate.
- 24. The method of claim 23, wherein said anodization is performed in a solution comprising oxalic acid, and said substrate is aluminum.
- 25. A method for production of a nanoscale particle array, comprising: a step of growing one or more metals or non-metals in a plurality of nanopores formed in a surface of a substrate.
 - 26. The method of claim 25, wherein said step of growing is preceded by a step of forming said plurality of nanopores in the surface of the substrate.
 - 27. A nanoscale particle array, comprising: a substrate having a plurality of nanopores in a surface thereof, and one or more metals or non-metals deposited in said plurality of nanopores to a depth of at least 5 nm and with coercivity of at least 500 Oe.
 - 28. The nanoscale particle array of claim 27, wherein said one or more metals are selected from the group consisting of magnetic metals, non-magnetic metals, semiconductors and metal oxides.
 - 29. The nanoscale particle array of claim 28, wherein said one or more metals are selected from the group consisting of magnetic metals and alloys thereof.
 - 30. The nanoscale particle array of claim 29, wherein said magnetic metals are selected from the group consisting of Fe, Co, Ni and alloys thereof.
 - 31. The nanoscale particle array of claim 27, wherein said substrate is aluminum.

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- 33. A magnetic information storage medium, comprising: a substrate having a plurality of nanopores in a surface thereof; and one or more metals deposited in said plurality of nanopores to a depth of at least 5 nm and with coercivity of at least 500 Oe, wherein the magnetic information storage medium has a recording density of at least 40 Gb/in²
- 34. The magnetic information storage medium of claim 33, wherein said one or more metals are selected from the group consisting of magnetic metals, metal oxides and magnetic metal alloys.
- 35. The magnetic information storage medium of claim 34, wherein said one or more metals are selected from the group consisting of magnetic metals and alloys thereof.
- 36. The magnetic information storage medium of claim 35, wherein said magnetic metals are selected from the group consisting of Fe, Co, Ni and alloys thereof.
- 37. The magnetic information storage medium of claim 33, wherein said substrate is aluminum.
- 38. The magnetic information storage medium of claim 33, wherein said plurality of nanopores are present in said substrate at a density of from 10⁶ to 10¹² cm⁻².
- 39. A magnetic information storage medium, comprising:
 - a substrate; and

 means for providing a recording density of at least 40 Gb/in² on a surface of said substrate.